Impact of the Use of Sterically Congested C^N Ligands on the Photoluminescent Properties of Iridium(III) Complexes Sciences Chimiques



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INTRODUCTION

Since the invention of artificial light, the quality, the performance and the energy efficiency of luminaires have been steadily improving, with organic light emitting diodes (OLEDs) emerging as one of the state-of-the-art artificial lighting technologies. However, OLEDs suffer from issues such as high production costs and small active surface areas. Another promising artificial lighting technology is the light emitting electrochemical cell (LEEC), with an emissive layer based on luminescent cationic iridium complexes. This device possesses a simpler architecture, which can lower significantly the production costs. Excited state selfquenching during the operation can limit the lifetime of the device. A strategy to circumvent this issue is to control the inter-nuclear distance by decorating the complexes with bulky, hydrophobic substituents.

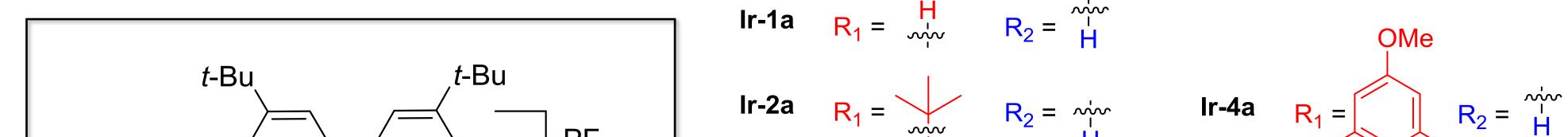
OBJECTIVES

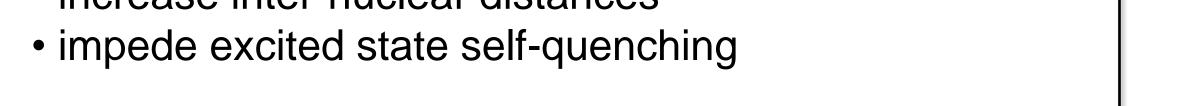
Design a family of cationic Iridium(III) complexes by modulating the size of substituents R_1 and R_2 on the C^N ligands. These groups will:

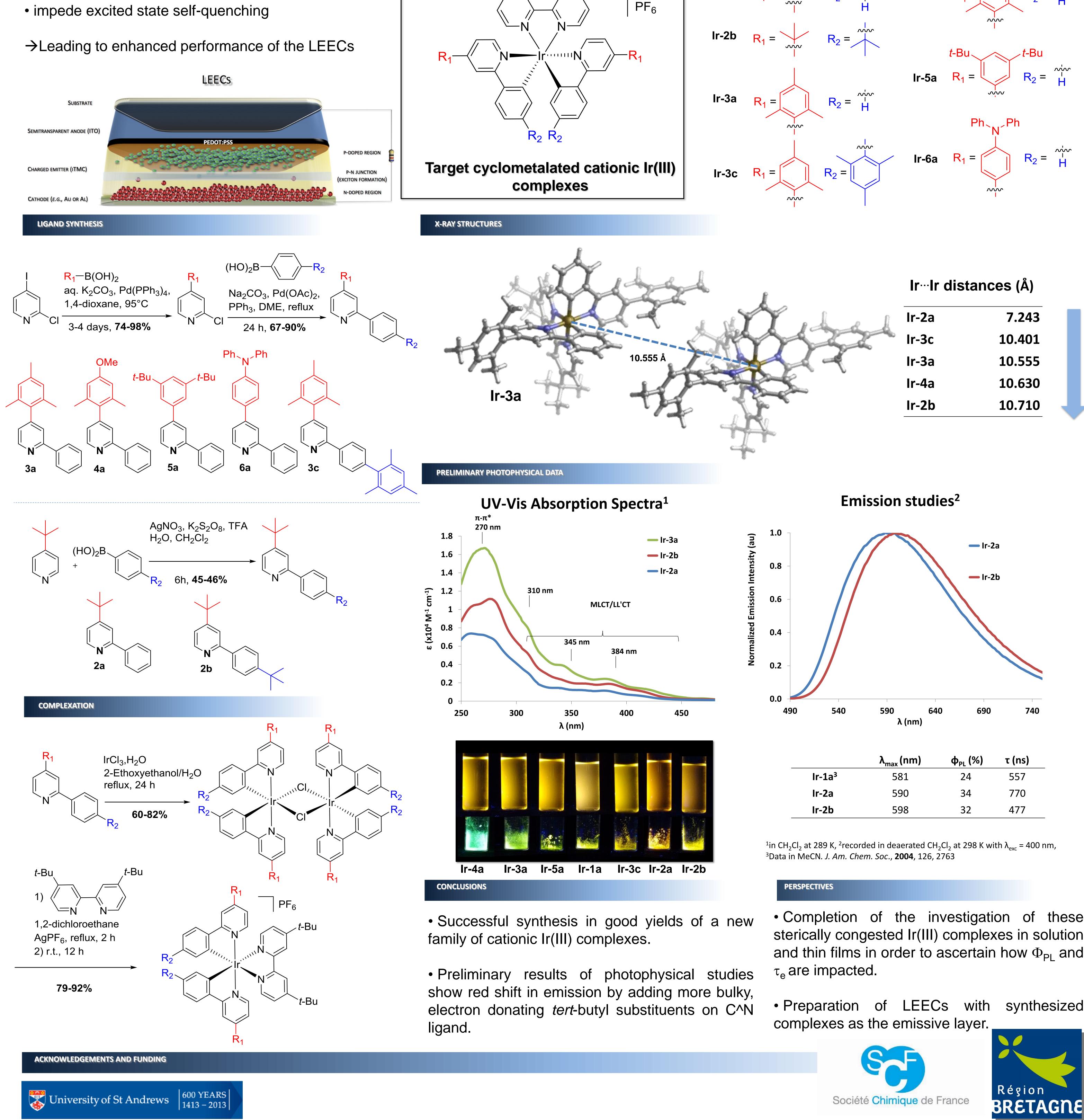
hinder disadvantageous attack

by small molecules in the film

• increase inter-nuclear distances







• Completion of the investigation of these sterically congested Ir(III) complexes in solution and thin films in order to ascertain how Φ_{PI} and

• Preparation of LEECs with synthesized

